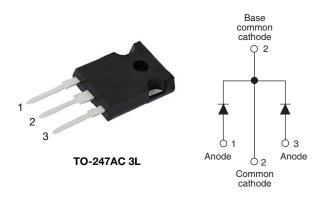
**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 2 x 30 A



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PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub> 2 x 30 A								
V <sub>R</sub>	45 V							
V <sub>F</sub> at I <sub>F</sub>	0.55 V							
I <sub>RM</sub> max.	150 mA at 125 °C							
T <sub>J</sub> max.	150 °C							
E <sub>AS</sub>	27 mJ							
Package	TO-247AC 3L							
Circuit configuration	Common cathode							

### FEATURES

- 150 °C T<sub>J</sub> operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- COMPLIANT HALOGEN
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-MBR6045WT... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	60	А						
V <sub>RRM</sub>		45	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	2900	А						
V <sub>F</sub>	30 $A_{pk}$ , $T_J$ = 125 °C (per leg)	0.55	V						
TJ		-55 to +150	°C						

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-MBR6045WT-N3	UNITS				
Maximum DC reverse voltage	V <sub>R</sub>	45	V				
Maximum working peak reverse voltage	V <sub>RWM</sub>	4	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forwardper legcurrent, see fig. 5per device		1	$50.\%$ duty avala at $T_{-} = 122.\%$		30				
		I <sub>F(AV)</sub>	50 % duty cycle at $T_C = 122 \circ C$	60					
Maximum peak one cycle non-repetitive surge current per leg, see fig. 7		leo, i	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	2900	A			
		IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	360				
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 4 A, L = 3.4 mH		27	mJ			
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		6	А			

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS						
		30 A	T <sub>.1</sub> = 25 °C	0.62					
Maximum forward voltage drop per leg See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	60 A	1j=25 C	0.75	V				
		30 A	T <sub>J</sub> = 125 °C	0.55					
Maximum reverse leakage current per leg	I (1)	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	1	mA				
See fig. 2	I <sub>RM</sub> (1)	T <sub>J</sub> = 125 °C	VR = naleu VR	150	ША				
Threshold voltage	V <sub>F(TO)</sub>			0.27	V				
Forward slope resistance	r <sub>t</sub>	$T_{\rm J} = T_{\rm J}$ maximum		7.3	mΩ				
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range	1400	pF					
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	7.5	nH					
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs					

### Note

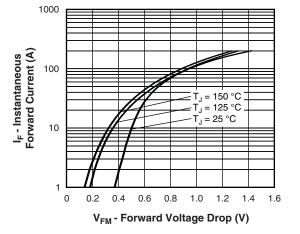
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

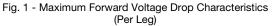
THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to 150	°C				
Maximum thermal resistance, junction to case per leg		Р	DC operation See fig. 4	1.0					
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub>	DC operation	0.5	°C/W				
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.24					
Approvimeto weight				6	g				
Approximate weight				0.21	oz.				
Mounting torque	minimum			6 (5)	kgf · cm				
Mounting torque	maximum			12 (10)	(lbf · in)				
Marking device			Case style TO-247AC 3L	MBR60	045WT				



# VS-MBR6045WT-N3

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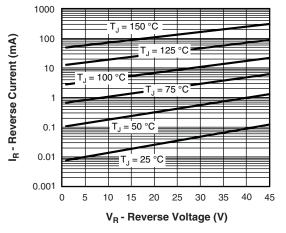


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

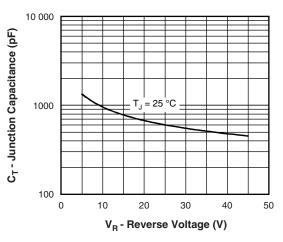


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

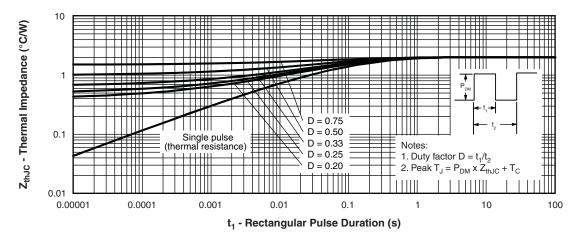


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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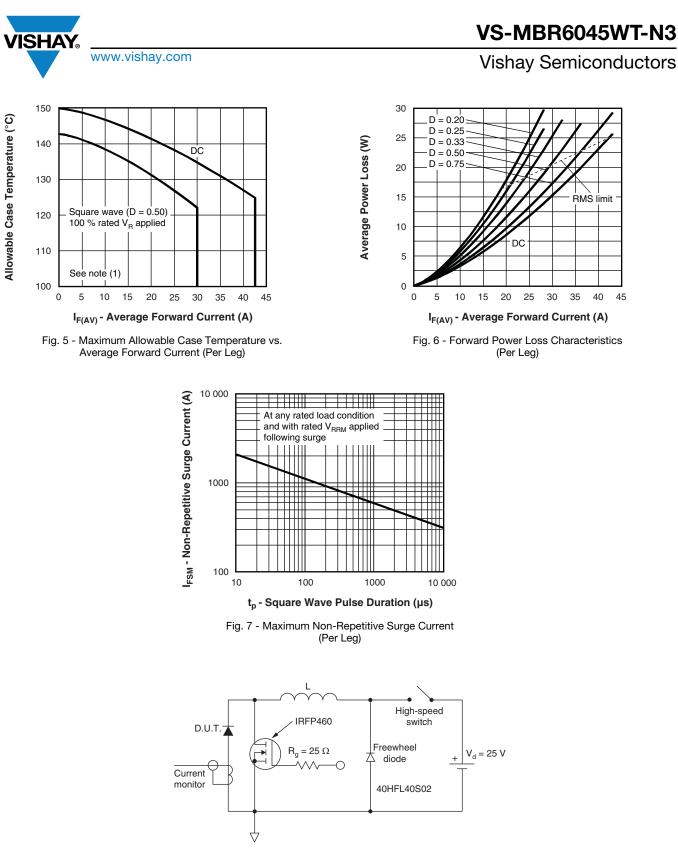


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{100} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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# **VS-MBR6045WT-N3**

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### **ORDERING INFORMATION TABLE**

Device code	VS-	MBR	60	45	₩Т	-N3
	1	2	3	4	5	6
	1 2		,	niconduc BR serie		duct
	3	- Cur	rent rati	ng (60 =	60 A)	
	<b>4</b>	- Volt	age rati	ng (45 =	45 V)	
	5			iguratior		
				(dual) T(		
	6			ntal digit gen-free		complia

ORDERING INFORMATION (Example)								
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION								
VS-MBR6045WT-N3	25	500	Antistatic plastic tube					

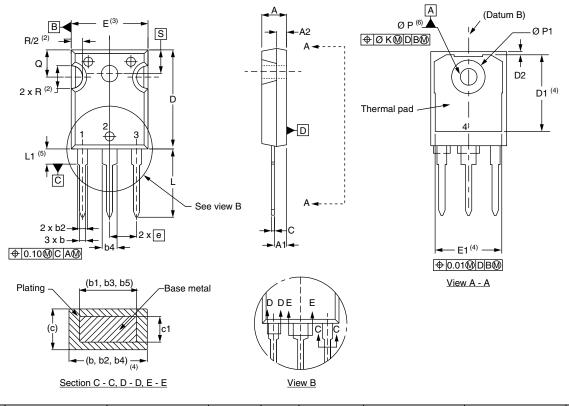
LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?96138						
Part marking information	www.vishay.com/doc?95007					



**Vishay Semiconductors** 

TO-247AC 3L

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWDOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209		D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102		E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054		E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055		е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053		ØК	0.2	254	0.0	)10	
b2	1.65	2.39	0.065	0.094		L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092		L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135		ØΡ	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133		Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035		Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033		R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3	S	5.51	BSC	0.217	' BSC	
D1	13.08	-	0.515	-	4						

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension Q

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